



WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 10 - 20 GHz

Typical Applications

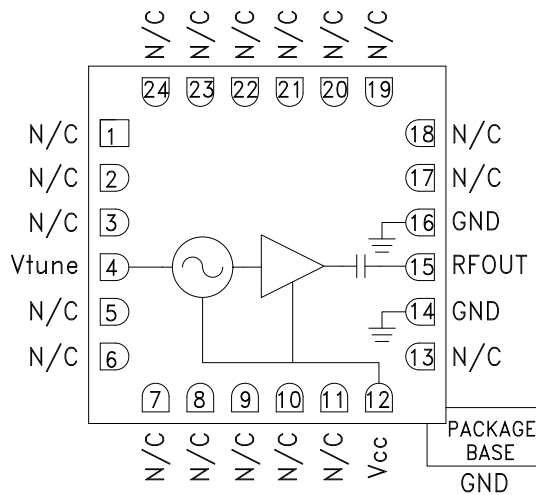
Low Noise wideband MMIC VCO is ideal for:

- Industrial/Medical Equipment
- Test & Measurement Equipment
- Military Radar, EW & ECM

Features

- Wide Tuning Bandwidth
- Pout: +3 dBm
- Low SSB Phase Noise: -90 dBc/Hz @100 kHz
- No External Resonator Needed
- Single Positive Supply: +5V @ 70 mA
- RoHS Compliant 4 x 4 mm SMT Package

Functional Diagram



General Description

The HMC733LC4B is a wideband MMIC Voltage Controlled Oscillator which incorporates the resonator, negative resistance device, and varactor diode. Output power and phase noise performance are excellent over temperature due to the oscillator's monolithic construction. The Vtune port accepts an analog tuning voltage from 0 to +22V. The HMC733LC4B VCO operates from a single +5V supply, consumes only 70 mA of current, and is housed in a RoHS compliant SMT package. This wideband VCO uniquely combines the attributes of ultra small size, low phase noise, low power consumption, and wide tuning range.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{CC} = +5\text{V}$

Parameter	Min.	Typ.	Max.	Units
Frequency Range		10 - 20		GHz
Power Output		3		dBm
SSB Phase Noise @ 10 kHz Offset		-60		dBc/Hz
SSB Phase Noise @ 100 kHz Offset		-90		dBc/Hz
Tune Voltage (Vtune)	-0.25		23	V
Supply Current (Icc) (Vcc = +5V)		70		mA
Tune Port Leakage Current (Vtune = +23V)		25		μA
Output Return Loss		10		dB
2nd Harmonic		-20		dBc
Pulling (into a 2.0:1 VSWR)		15		MHz pp
Vcc Pushing, Vtune = +20V, F = 20 GHz		-90		MHz/V
Frequency Drift Rate @ 10 GHz		-0.25		MHz/ $^\circ\text{C}$
Frequency Drift Rate @ 20 GHz		-0.80		MHz/ $^\circ\text{C}$

HMC733* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- HMC733LC4B Evaluation Board

DOCUMENTATION

Data Sheet

- HMC733 Data Sheet

REFERENCE MATERIALS

Quality Documentation

- Package/Assembly Qualification Test Report: LC4, LC4B (QTR: 2014-00380 REV: 01)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

DESIGN RESOURCES

- HMC733 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC733 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

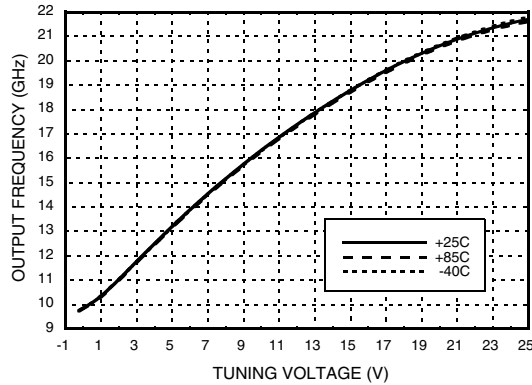
DOCUMENT FEEDBACK

Submit feedback for this data sheet.

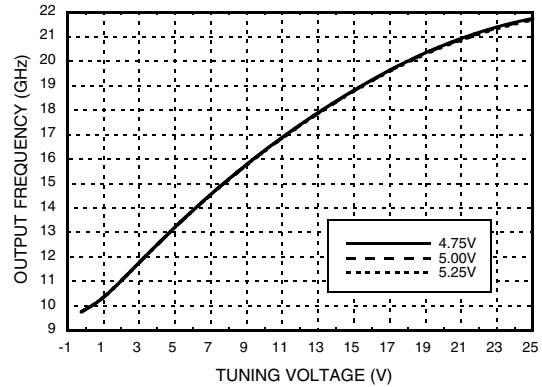


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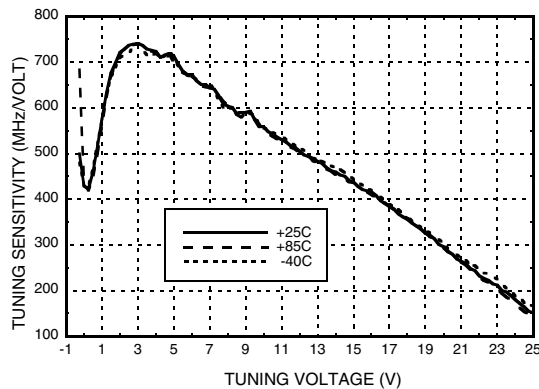
Frequency vs. Tuning Voltage, Vcc = +5V



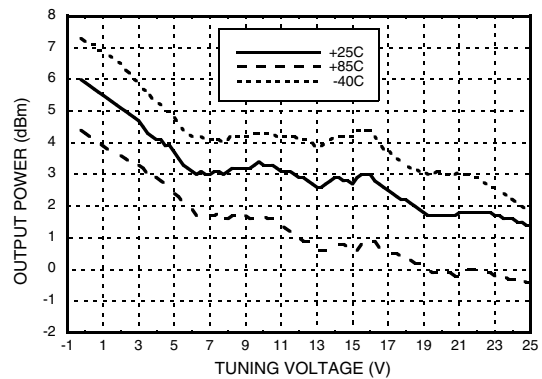
Frequency vs. Tuning Voltage, T = +25 °C



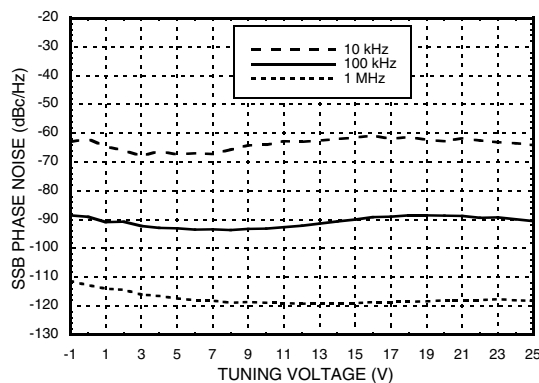
Sensitivity vs. Tuning Voltage, Vcc = +5V, T = +25 °C



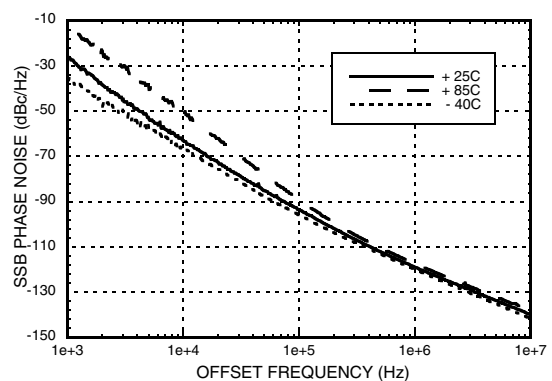
Output Power vs. Tuning Voltage, Vcc = +5V



SSB Phase Noise vs. Tuning Voltage, T = +25 °C



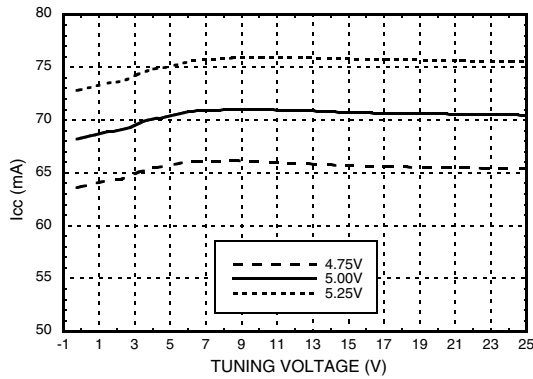
Typical SSB Phase Noise vs. Temperature Vtune = +10V





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Supply Current vs. Vcc, T = +25 °C



Absolute Maximum Ratings

Vcc	+5.5 Vdc
Vtune	-1.0 to +25V
Storage Temperature	-65 to +150 °C
ESD Sensitivity (HBM)	Class 1A

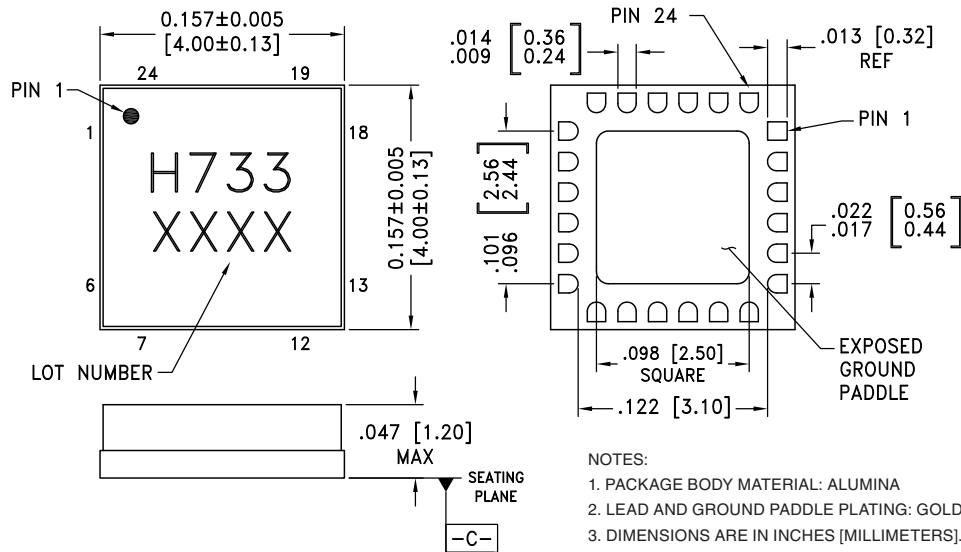
Reliability Information

Junction Temperature To Maintain 1 Million Hour MTTF	135 °C
Nominal Junction Temperature (T = 85 °C)	119 °C
Thermal Resistance (Junction to GND paddle, 5V supply)	97 °C/W
Operating Temperature	-40 °C to +85 °C



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



- NOTES:
1. PACKAGE BODY MATERIAL: ALUMINA
 2. LEAD AND GROUND PADDLE PLATING: GOLD FLASH OVER NI.
 3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-
 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

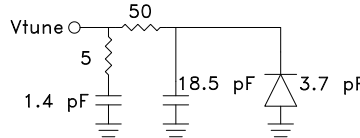
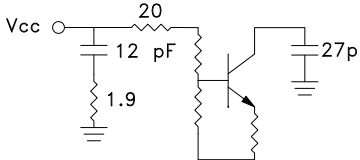

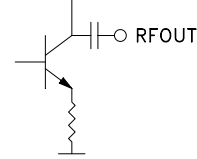
Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC733LC4B	Alumina, White	Gold over Nickel	MSL3 [1]	H733 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

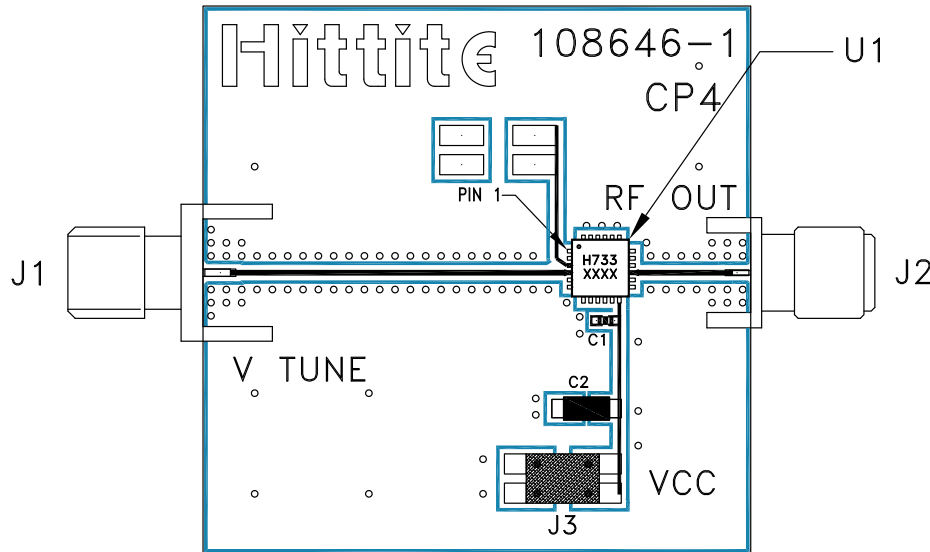

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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1 - 3, 5 - 11, 13, 17 - 24	N/C	No Connection. These pins may be connected to RF/DC ground. Performance will not be affected.	
4	Vtune	Control Voltage and Modulation Input. Modulation bandwidth dependent on drive source impedance.	
12	Vcc	Supply Voltage Vcc= +5V	
14, 16	GND	Package bottom has an exposed metal paddle that must also be RF & DC grounded.	
15	RFOUT	RF output (AC coupled)	



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Evaluation PCB



List of Materials for Evaluation PCB 108648 [1]

Item	Description
J1	PCB Mount SMA RF Connector, Johnson
J2	PCB Mount SMA Connector, SRI
J3	DC Header
C1	1000 pF Capacitor, 0402 Pkg.
C2	4.7 μF Capacitor, Tantalum
U1	HMC733LC4B VCO
PCB [2]	108646 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed ground paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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